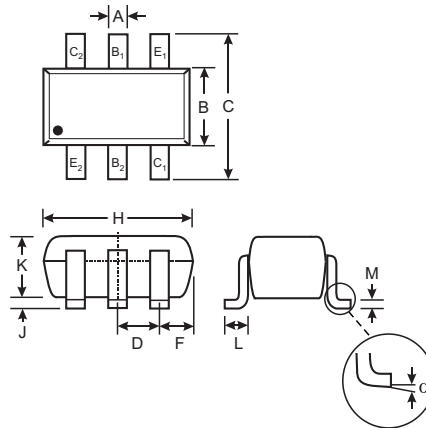


### Features

- Complementary Pair
- Epitaxial Planar Die Construction
- One 2222A Type (NPN),
- One 2907A Type (PNP)
- Ideal for Low Power Amplification and Switching
- Lead Free By Design/RoHS Compliant (Note 2)**
- "Green Device" (Note 3)**

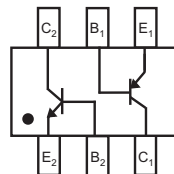


SOT-26			
Dim	Min	Max	Typ
A	0.35	0.50	0.38
B	1.50	1.70	1.60
C	2.70	3.00	2.80
D			0.95
F			0.55
H	2.90	3.10	3.00
J	0.013	0.10	0.05
K	1.00	1.30	1.10
L	0.35	0.55	0.40
M	0.10	0.20	0.15
	0	8	
<b>All Dimensions in mm</b>			

### Mechanical Data

- Case: SOT-26
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Finish - Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Ordering & Date Code Information: See Page 3
- Marking (See Page 3): K27
- Weight: 0.006 grams (approximate)

Note: E1, B1, and C1 = 2907A Type (PNP),  
E2, B2, and C2 = 2222A Type (NPN).  
Type marking indicates orientation.



### Maximum Ratings, 2222A Type (NPN)

@ T<sub>A</sub> = 25 C unless otherwise specified

Characteristic	Symbol	2222A (NPN)	Unit
Collector-Base Voltage	V <sub>CBO</sub>	75	V
Collector-Emitter Voltage	V <sub>CEO</sub>	40	V
Emitter-Base Voltage	V <sub>EBO</sub>	6.0	V
Collector Current - Continuous	I <sub>C</sub>	600	mA

### Maximum Ratings, 2907A Type (PNP)

@ T<sub>A</sub> = 25 C unless otherwise specified

Characteristic	Symbol	2907A (PNP)	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-60	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-60	V
Emitter-Base Voltage	V <sub>EBO</sub>	-5.0	V
Collector Current - Continuous	I <sub>C</sub>	-600	mA

### Maximum Ratings, Total

@ T<sub>A</sub> = 25 C unless otherwise specified

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 1)	P <sub>d</sub>	300	mW
Thermal Resistance, Junction to Ambient (Note 1)	R <sub>JA</sub>	417	C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	C

- Note:
- Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at <http://www.diodes.com/datasheets/ap02001.pdf>.
  - No purposefully added lead.
  - Diodes Inc.'s "Green" policy can be found on our website at [http://www.diodes.com/products/lead\\_free/index.php](http://www.diodes.com/products/lead_free/index.php).

**Electrical Characteristics, 2222A Type (NPN)**

 @ T<sub>A</sub> = 25 C unless otherwise specified

Characteristic	Symbol	Min	Max	Unit	Test Condition
<b>OFF CHARACTERISTICS (Note 4)</b>					
Collector-Base Breakdown Voltage	V <sub>(BR)CBO</sub>	75		V	I <sub>C</sub> = 10 A, I <sub>E</sub> = 0
Collector-Emitter Breakdown Voltage	V <sub>(BR)CEO</sub>	40		V	I <sub>C</sub> = 10mA, I <sub>B</sub> = 0
Emitter-Base Breakdown Voltage	V <sub>(BR)EBO</sub>	6.0		V	I <sub>E</sub> = 10 A, I <sub>C</sub> = 0
Collector Cutoff Current	I <sub>CBO</sub>		10	nA A	V <sub>CB</sub> = 60V, I <sub>E</sub> = 0 V <sub>CB</sub> = 60V, I <sub>E</sub> = 0, T <sub>A</sub> = 150 C
Collector Cutoff Current	I <sub>CEX</sub>		10	nA	V <sub>CE</sub> = 60V, V <sub>EB(OFF)</sub> = 3.0V
Emitter Cutoff Current	I <sub>EBO</sub>		10	nA	V <sub>EB</sub> = 3.0V, I <sub>C</sub> = 0
Base Cutoff Current	I <sub>BL</sub>		20	nA	V <sub>CE</sub> = 60V, V <sub>EB(OFF)</sub> = 3.0V
<b>ON CHARACTERISTICS (Note 4)</b>					
DC Current Gain	h <sub>FE</sub>	35 50 75 100 40 50 35	300		I <sub>C</sub> = 100 A, V <sub>CE</sub> = 10V I <sub>C</sub> = 1.0mA, V <sub>CE</sub> = 10V I <sub>C</sub> = 10mA, V <sub>CE</sub> = 10V I <sub>C</sub> = 150mA, V <sub>CE</sub> = 10V I <sub>C</sub> = 500mA, V <sub>CE</sub> = 10V I <sub>C</sub> = 10mA, V <sub>CE</sub> = 10V, T <sub>A</sub> = -55 C I <sub>C</sub> = 150mA, V <sub>CE</sub> = 1.0V
Collector-Emitter Saturation Voltage	V <sub>CE(SAT)</sub>		0.3 1.0	V	I <sub>C</sub> = 150mA, I <sub>B</sub> = 15mA I <sub>C</sub> = 500mA, I <sub>B</sub> = 50mA
Base-Emitter Saturation Voltage	V <sub>BE(SAT)</sub>	0.6	1.2 2.0	V	I <sub>C</sub> = 150mA, I <sub>B</sub> = 15mA I <sub>C</sub> = 500mA, I <sub>B</sub> = 50mA
<b>SMALL SIGNAL CHARACTERISTICS</b>					
Output Capacitance	C <sub>obo</sub>		8	pF	V <sub>CB</sub> = 10V, f = 1.0MHz, I <sub>E</sub> = 0
Input Capacitance	C <sub>ibo</sub>	—	25	pF	V <sub>EB</sub> = 0.5V, f = 1.0MHz, I <sub>C</sub> = 0
Current Gain-Bandwidth Product	f <sub>T</sub>	300		MHz	V <sub>CE</sub> = 20V, I <sub>C</sub> = 20mA, f = 100MHz
<b>SWITCHING CHARACTERISTICS</b>					
Delay Time	t <sub>d</sub>		10	ns	V <sub>CC</sub> = 30V, I <sub>C</sub> = 150mA, V <sub>BE(off)</sub> = - 0.5V, I <sub>B1</sub> = 15mA
Rise Time	t <sub>r</sub>		25	ns	
Storage Time	t <sub>s</sub>		225	ns	V <sub>CC</sub> = 30V, I <sub>C</sub> = 150mA, I <sub>B1</sub> = I <sub>B2</sub> = 15mA
Fall Time	t <sub>f</sub>		60	ns	

Note: 4. Pulse test: Pulse width 300 s, duty cycle 2%.

## Electrical Characteristics, 2907A Type (PNP) @ $T_A = 25\text{ C}$ unless otherwise specified

Characteristic	Symbol	Min	Max	Unit	Test Condition
<b>OFF CHARACTERISTICS (Note 5)</b>					
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	-60		V	$I_C = -10\text{ A}, I_E = 0$
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	-60		V	$I_C = -10\text{mA}, I_B = 0$
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	-5.0		V	$I_E = -10\text{ A}, I_C = 0$
Collector Cutoff Current	$I_{CBO}$		-10	nA A	$V_{CB} = -50\text{V}, I_E = 0$ $V_{CB} = -50\text{V}, I_E = 0, T_A = 125\text{ C}$
Collector Cutoff Current	$I_{CEX}$		-50	nA	$V_{CE} = -30\text{V}, V_{EB(OFF)} = -0.5\text{V}$
Base Cutoff Current	$I_{BL}$		-50	nA	$V_{CE} = -30\text{V}, V_{EB(OFF)} = -0.5\text{V}$
<b>ON CHARACTERISTICS (Note 5)</b>					
DC Current Gain	$h_{FE}$	75 100 100 100 50	300		$I_C = -100\mu\text{A}, V_{CE} = -10\text{V}$ $I_C = -1.0\text{mA}, V_{CE} = -10\text{V}$ $I_C = -10\text{mA}, V_{CE} = -10\text{V}$ $I_C = -150\text{mA}, V_{CE} = -10\text{V}$ $I_C = -500\text{mA}, V_{CE} = -10\text{V}$
Collector-Emitter Saturation Voltage	$V_{CE(SAT)}$		-0.4 -1.6	V	$I_C = -150\text{mA}, I_B = -15\text{mA}$ $I_C = -500\text{mA}, I_B = -50\text{mA}$
Base-Emitter Saturation Voltage	$V_{BE(SAT)}$		-1.3 -2.6	V	$I_C = 150\text{mA}, I_B = 15\text{mA}$ $I_C = 500\text{mA}, I_B = 50\text{mA}$
<b>SMALL SIGNAL CHARACTERISTICS</b>					
Output Capacitance	$C_{obo}$		8.0	pF	$V_{CB} = -10\text{V}, f = 1.0\text{MHz}, I_E = 0$
Input Capacitance	$C_{ibo}$	—	30	pF	$V_{EB} = -2.0\text{V}, f = 1.0\text{MHz}, I_C = 0$
Current Gain-Bandwidth Product	$f_T$	200		MHz	$V_{CE} = -20\text{V}, I_C = -50\text{mA}, f = 100\text{MHz}$
<b>SWITCHING CHARACTERISTICS</b>					
Turn-On Time	$t_{on}$		45	ns	$V_{CC} = -30\text{V}, I_C = -150\text{mA}, I_{B1} = -15\text{mA}$
Delay Time	$t_d$		10	ns	
Rise Time	$t_r$		40	ns	
Turn-Off Time	$t_{off}$		100	ns	$V_{CC} = -6.0\text{V}, I_C = -150\text{mA}, I_{B1} = I_{B2} = -15\text{mA}$
Storage Time	$t_s$		80	ns	
Fall Time	$t_f$		30	ns	

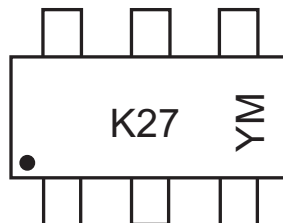
Note: 5. Short duration pulse test used to minimize self-heating effect.

## Ordering Information (Note 6)

Device	Packaging	Shipping
MMDT2227M-7	SOT-26	3000/Tape & Reel

Note: 6. For Packaging Details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

## Marking Information



K27 = Product Type Marking Code  
 YM = Date Code Marking  
 Y = Year ex: S = 2005  
 M = Month ex: 9 = September

Date Code Key

Year	2005	2006	2007	2008	2009	2010	2011	2012
Code	S	T	U	V	W	X	Y	Z

Month	Jan	Feb	March	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

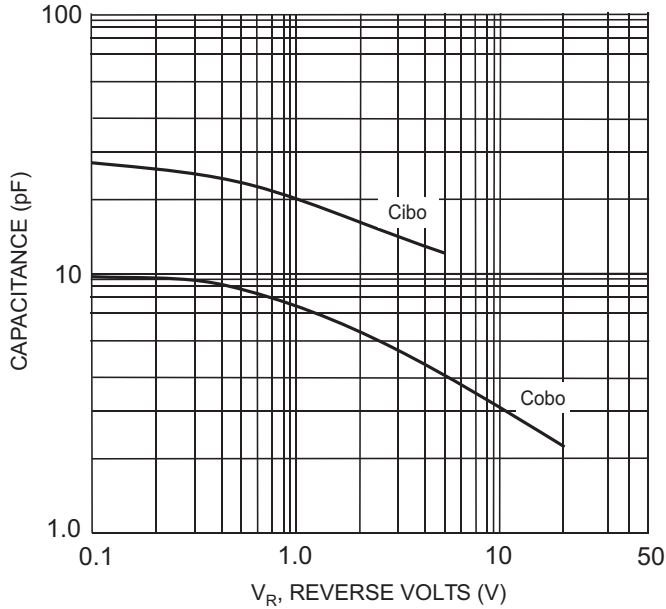


Fig. 1 (2222A) Typical Capacitance

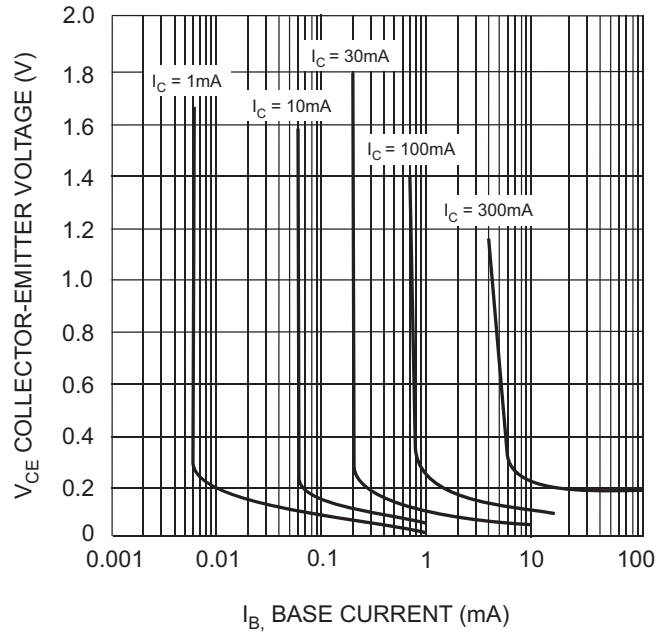


Fig. 2 (2222A) Typical Collector Saturation Region

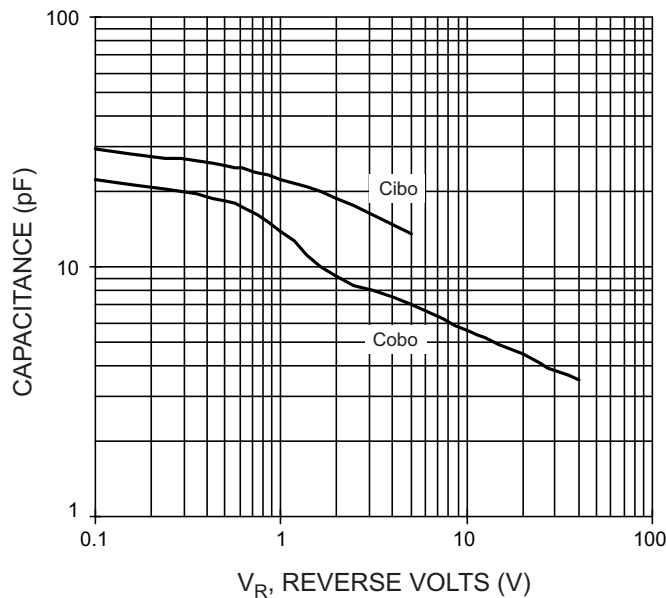


Fig. 3 (2907A) Typical Capacitance

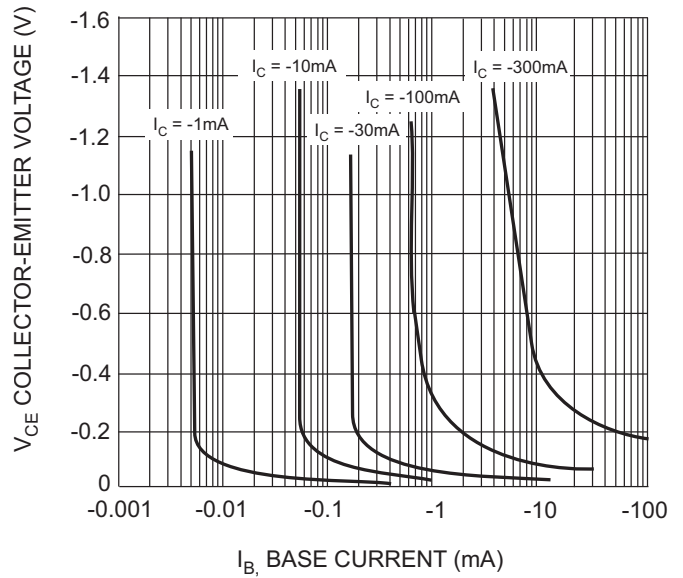


Fig. 4 (2907A) Typical Collector Saturation Region

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